

FFP08S60S

Features

- High Speed Switching, t_{rr} < 30ns @ I_F=8A
- · High Reverse Voltage and High Reliability
- RoHS component

Applications

- · General Purpose
- Switching Mode Power Supply
- Boost Diode in continuous mode power factor corrections
- · Power switching circuits



STEALTHTM II Rectifier

8A, 600V STEALTH™ II Rectifier

The FFP08S60S is STEALTH™ II rectifier with soft recovery characteristics. It is silicon nitride passivated ion-implanted epitaxial planar construction.

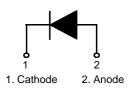
This device is intended for use as freewheeling of boost diode in switching power supplies and other power switching applications. Their low stored charge and hyperfast soft recovery minimize ringing and electrical noise in many power switching circuits reducing power loss in the switching transistors.

Pin Assignments



1. Cathode

2. Anode



Absolute Maximum Ratings T_C = 25°C unless otherwise noted

Symbol	Parameter	Value	Units	
V _{RRM}	Peak Repetitive Reverse Voltage	600	V	
V _{RWM}	Working Peak Reverse Voltage	600	V	
V _R	DC Blocking Voltage	600	V	
I _{F(AV)}	Average Rectified Forward Current @ T _C = 115 °C	8	Α	
I _{FSM}	Non-repetitive Peak Surge Current 60Hz Single Half-Sine Wave	80	А	
T _{J,} T _{STG}	Operating Junction and Storage Temperature	- 65 to +150	°C	

Thermal Characteristics

Symbol	Parameter	Max	Units
$R_{\theta JC}$	Maximum Thermal Resistance, Junction to Case	2.5	°C/W

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
F08S60S	FFP08S60STU	TO-220-2L	-	-	50

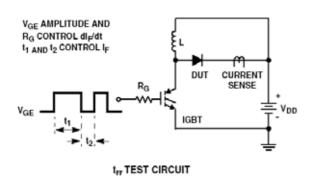
Electrical Characteristics $T_C = 25^{\circ}C$ unless otherwise noted

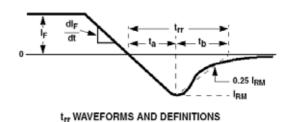
Parameter	Conditions			Тур.	Max	Units
V _{FM} ¹	I _F = 8A I _F = 8A	T _C = 25 °C T _C = 125 °C	-	2.1 1.6	2.6 -	V V
I _{RM} ¹	$V_R = 600V$ $V_R = 600V$	$T_C = 25 ^{\circ}C$ $T_C = 125 ^{\circ}C$	-	-	100 500	μA μA
t _{rr}	$I_F = 1A$, di/dt = 100A/ μ s, $V_R = 30V$	T _C = 25 °C	-	-	25	ns
trr Irr S factor Q _{rr}	$I_F = 8A$, di/dt = 200A/ μ s, $V_R = 390V$	T _C = 25 °C	- - -	19 2.2 0.6 21	30 - - -	ns A nC
trr Irr S factor Q _{rr}	$I_F = 8A$, di/dt = 200A/ μ s, $V_R = 390V$	T _C = 125 °C	- - - -	58 4.3 1.3 125	- - -	ns A nC
W _{AVL}	Avalanche Energy (L = 40mH)		20	-	-	mJ

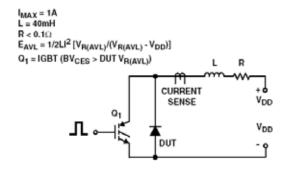
Notes:

1. Pulse : Test Pulse width = 300μ s, Duty Cycle = 2%

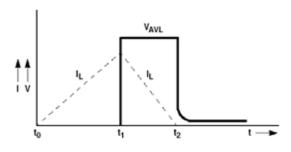
Test Circuit and Waveforms







AVALANCHE ENERGY TEST CIRCUIT



AVALANCHE CURRENT AND VOLTAGE WAVEFORMS

Typical Performance Characteristics T_C = 25°C unless otherwise noted

Figure 1. Typical Forward Voltage Drop

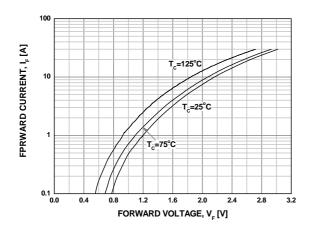


Figure 2. Typical Reverse Current

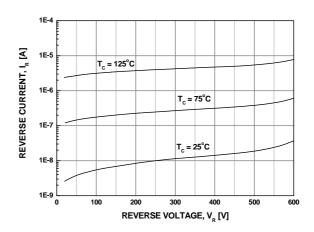


Figure 3. Typical Junction Capacitance

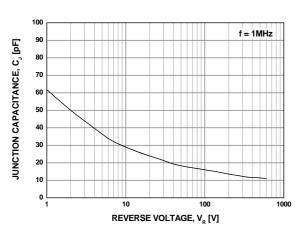


Figure 4. Typical Reverse Recovery Time

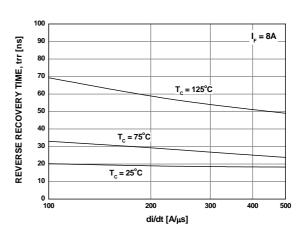


Figure 5. Typical Reverse Recovery Current

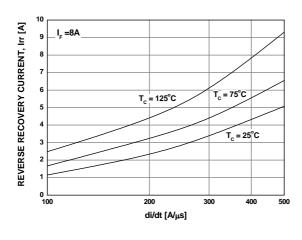
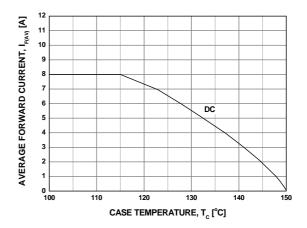
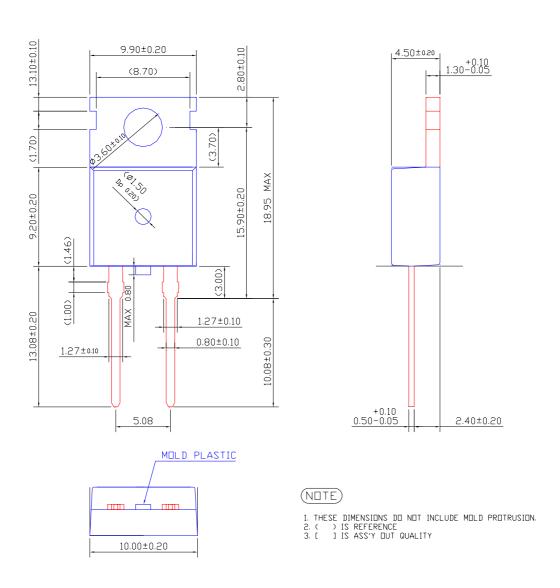


Figure 6. Forward Current Deration Curve



Mechanical Dimensions

TO-220-2L



Dimensions in Millimeters





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